NSN 5962-01-360-4067

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View Online at https://aerobasegroup.com/nsn/5962-01-360-4067

Body Length:

Between 1.635 inches and 1.680 inches

Body Width:

Between 0.565 inches and 0.605 inches

Body Height:

Between 0.160 inches and 0.220 inches

Operating Tempurature Range:

-55.0/+125.0 degrees celsius

Storage Tempurature Range:

-65.0/+150.0 degrees celsius

End Application:

Ac/rmpe react basic

Features Provided:

Programmed and ultraviolet erasable and electrostatic sensitive and monolithic

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Criticality Code Justification:

Feat

Terminal Surface Treatment:

Solder

Product Name:

Microcircuit, epro (27c10)

Voltage Rating And Type Per Characteristic:

-0.6 volts power source and 7.0 volts power source

Time Rating Per Chacteristic:

170.00 nanoseconds af output megawatts

Memory Device Type:

Programmed

Memory Capacity:

128 x8

Special Features:

Esd rating: class 1 (1000volts); selected item from 34335 5962-896

Nuclear Hardness Critical Feature:

Hardened

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

32 beam lead

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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